

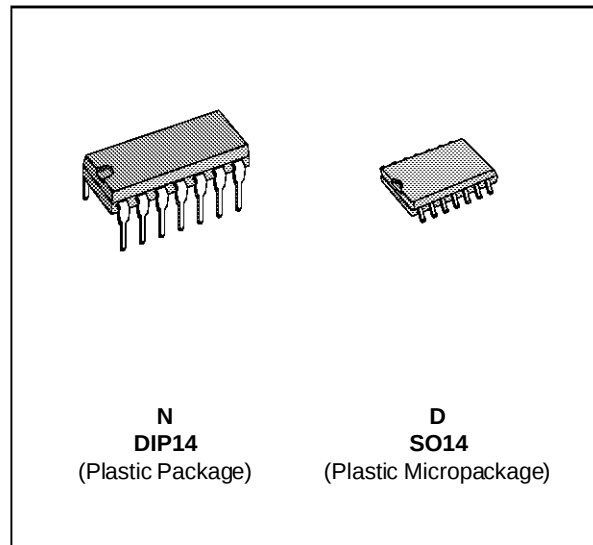


GENERAL PURPOSE DUAL BIPOLAR TIMERS

- LOW TURN OFF TIME
- MAXIMUM OPERATING FREQUENCY GREATER THAN 500kHz
- TIMING FROM MICROSECONDS TO HOURS
- OPERATES IN BOTH ASTABLE AND MONOSTABLE MODES
- HIGH OUTPUT CURRENT CAN SOURCE OR SINK 200mA
- ADJUSTABLE DUTY CYCLE
- TTL COMPATIBLE
- TEMPERATURE STABILITY OF 0.005% PER °C

DESCRIPTION

The NE556 dual monolithic timing circuit is a highly stable controller capable of producing accurate time delays or oscillation. In the time delay mode of operation, the time is precisely controlled by one external resistor and capacitor. For a stable operation as an oscillator, the free running frequency and the duty cycle are both accurately controlled with two external resistors and one capacitor. The circuit may be triggered and reset on falling waveforms, and the output structure can source or sink up to 200mA.

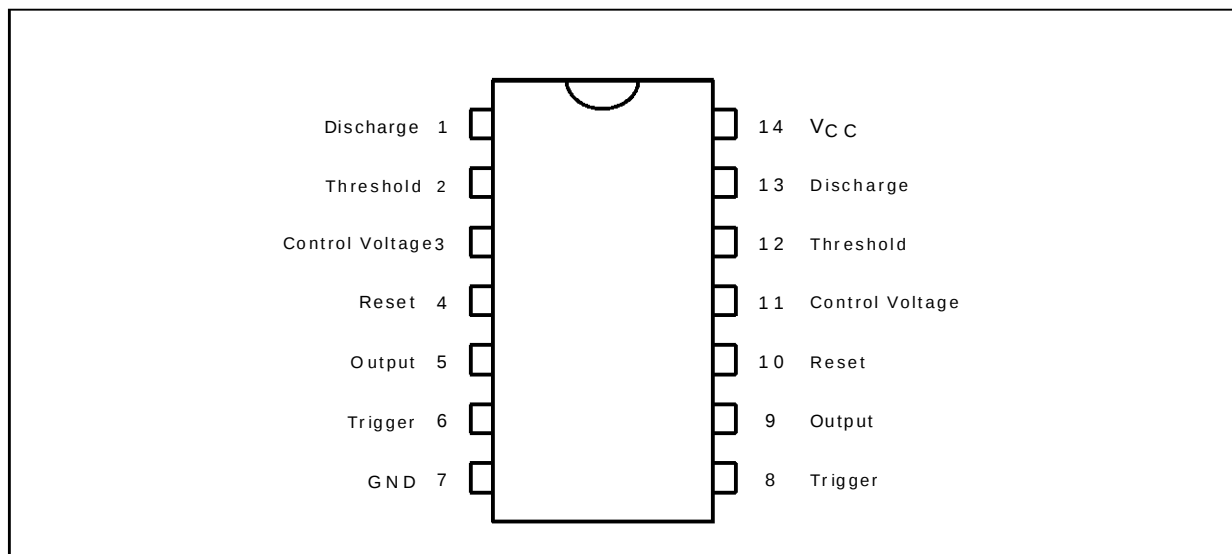


ORDER CODES

Part Number	Temperature Range	Package	
		N	D
NE556	0°C, 70°C	•	•
SA556	-40°C, 105°C	•	•
SE556	-55°C, 125°C	•	•

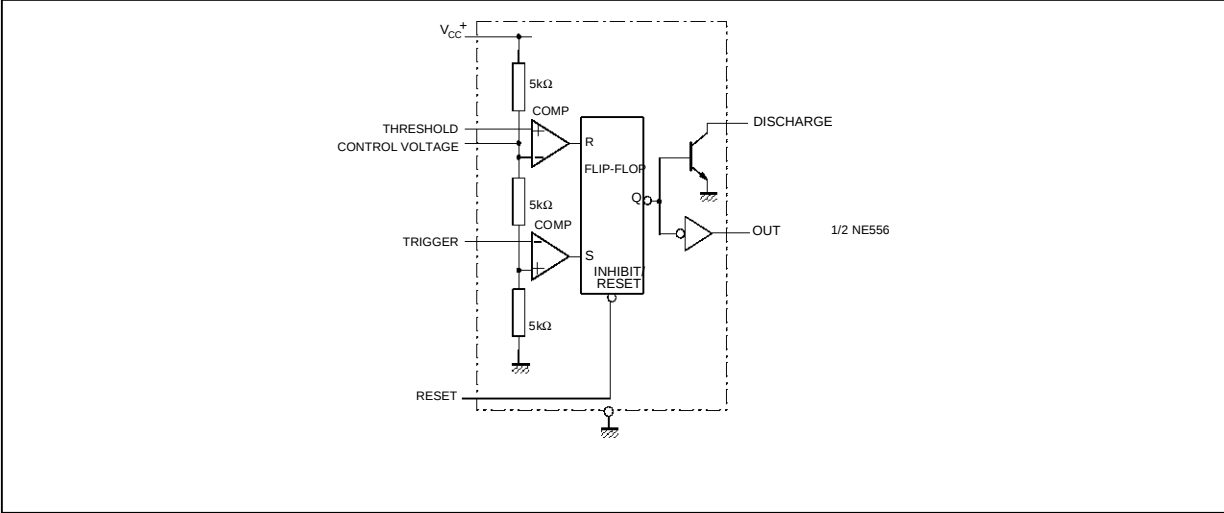
556-01.TBL

PIN CONNECTIONS (top view)

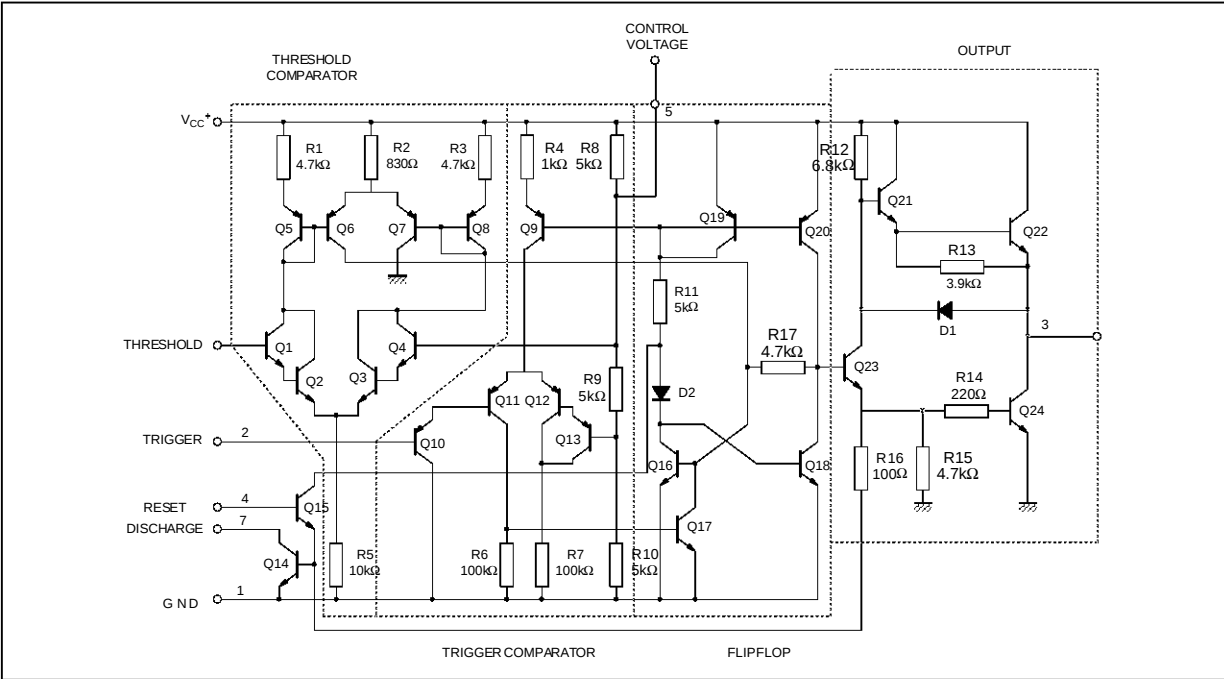


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BLOCK DIAGRAM



SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{cc}	Supply Voltage	for SE556 for NE556	18 16	V
T_{oper}	Operating Free Air Temperature Range	for NE556 for SA556 for SE556	0 to 70 -40 to 105 -55 to 125	°C
T_j	Junction Temperature		150	°C

OPERATING CONDITIONS

Symbol	Parameter	SE556	NE556 - SA556	Unit
V_{CC}	Supply Voltage	4.5 to 18	4.5 to 16	V
V_{th} , V_{trig} , V_{cl} , V_{reset}	Maximum Input Voltage	V_{CC}	V_{CC}	V

556-03.TBL

ELECTRICAL CHARACTERISTICS

$T_{amb} = +25^{\circ}\text{C}$, $V_{CC} = +5\text{V}$ to $+15\text{V}$ (unless otherwise specified)

Symbol	Parameter	SE556			NE556 - SA556			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
I_{CC}	Supply Current ($R_L \infty$) - (note 1) - (2 timers) Low State $V_{CC} = +5\text{V}$ $V_{CC} = +15\text{V}$ High State $V_{CC} = 5\text{V}$		6 20 4	10 24		6 20 4	12 30	mA
	Timing Error (monostable) ($R_A = 2\text{k}$ to $100\text{k}\Omega$, $C = 0.1\mu\text{F}$) Initial Accuracy - (note 2) Drift with Temperature Drift with Supply Voltage		0.5 30 0.05	2 100 0.2		1 50 0.1	3 0.5	% ppm/ $^{\circ}\text{C}$ %/V
	Timing Error (astable) ($R_A, R_B = 1\text{k}\Omega$ to $100\text{k}\Omega$, $C = 0.1\mu\text{F}$, $V_{CC} = +15\text{V}$) Initial Accuracy - (note 2) Drift with Temperature Drift with Supply Voltage		1.5 90 0.15			2.25 150 0.3		% ppm/ $^{\circ}\text{C}$ %/V
V_{CL}	Control Voltage level $V_{CC} = +15\text{V}$ $V_{CC} = +5\text{V}$	9.6 2.9	10 3.33	10.4 3.8	9 2.6	10 3.33	11 4	V
V_{th}	Threshold Voltage $V_{CC} = +15\text{V}$ $V_{CC} = +5\text{V}$	9.4 2.7	10 3.33	10.6 4	8.8 2.4	10 3.33	11.2 4.2	V
I_{th}	Threshold Current - (note 3)		0.1	0.25		0.1	0.25	μA
V_{trig}	Trigger Voltage $V_{CC} = +15\text{V}$ $V_{CC} = +5\text{V}$	4.8 1.45	5 1.67	5.2 1.9	4.5 1.1	5 1.67	5.6 2.2	V
I_{trig}	Trigger Current ($V_{trig} = 0\text{V}$)		0.5	0.9		0.5	2.0	μA
V_{reset}	Reset Voltage - (note 4)	0.4	0.7	1	0.4	0.7	1	V
I_{reset}	Reset Current $V_{reset} = +0.4\text{V}$ $V_{reset} = 0\text{V}$		0.1 0.4	0.4 1		0.1 0.4	0.4 1.5	mA
V_{OL}	Low Level Output Voltage $V_{CC} = +15\text{V}$, $I_{O(sink)} = 10\text{mA}$ $I_{O(sink)} = 50\text{mA}$ $I_{O(sink)} = 100\text{mA}$ $I_{O(sink)} = 200\text{mA}$ $V_{CC} = +5\text{V}$, $I_{O(sink)} = 8\text{mA}$ $I_{O(sink)} = 5\text{mA}$		0.1 0.4 2 2.5 0.1 0.05	0.15 0.5 2.2		0.1 0.4 2 2.5 0.3 0.25	0.25 0.75 2.5 0.4 0.35	V
V_{OH}	High Level Output Voltage $V_{CC} = +15\text{V}$, $I_{O(source)} = 200\text{mA}$ $I_{O(source)} = 100\text{mA}$ $V_{CC} = +5\text{V}$, $I_{O(source)} = 100\text{mA}$	13 3	12.5 13.3 3.3		12.75 2.75	12.5 13.3 3.3		V

556-4.TBL

- Notes :**
1. Supply current when output is high is typically 1mA less.
 2. Tested at $V_{CC} = +5\text{V}$ and $V_{CC} = +15\text{V}$.
 3. This will determine the maximum value of $R_A + R_B$ for +15V operation the max total is $R = 20\text{M}\Omega$ and for 5V operation, the max total $R = 3.5\text{M}\Omega$.
 4. Specified with trigger input high.

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	SE556			NE556 - SA556			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
$I_{dis(off)}$	Discharge Pin Leakage Current (output high) ($V_{dis} = 10V$)		20	100		20	100	nA
$V_{dis(sat)}$	Discharge pin Saturation Voltage (output low) - (note 5) $V_{CC} = +15V$, $I_{dis} = 15mA$ $V_{CC} = +5V$, $I_{dis} = 4.5mA$		180 80	480 200		180 80	480 200	mV
t_r t_f	Output Rise Time Output Fall Time		100 100	200 200		100 100	300 300	ns
t_{off}	Turn off Time - (note 6) ($V_{reset} = V_{CC}$)		0.5			0.5		μs

- Notes :
5. No protection against excessive Pin 7 current is necessary, providing the package dissipation rating will not be exceeded.
 6. Time measured from a positive going input pulse from 0 to $0.8 \times V_{CC}$ into the threshold to the drop from high to low of the output trigger is tied to threshold.

Figure 1 : Minimum Pulse Width Required for Trigering

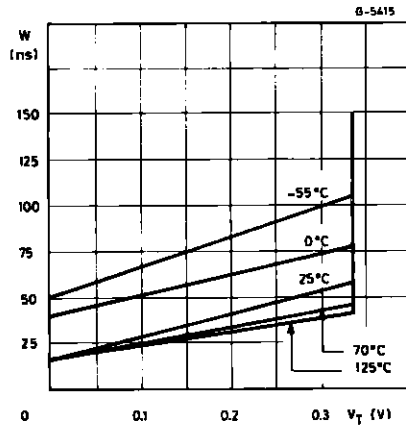


Figure 2 : Supply Current versus Supply Voltage

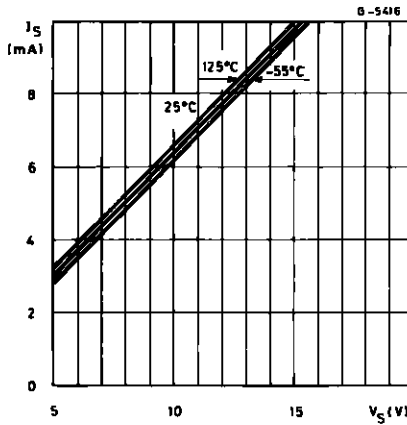


Figure 3 : Delay Time versus Temperature

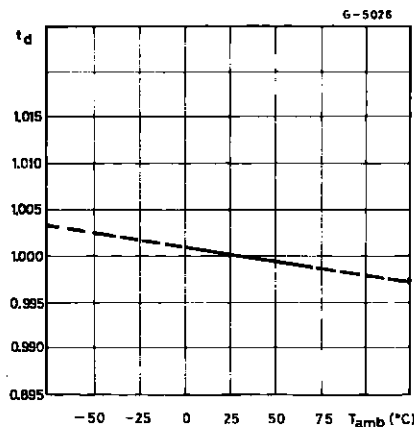


Figure 4 : Low Output Voltage versus Output Sink Current

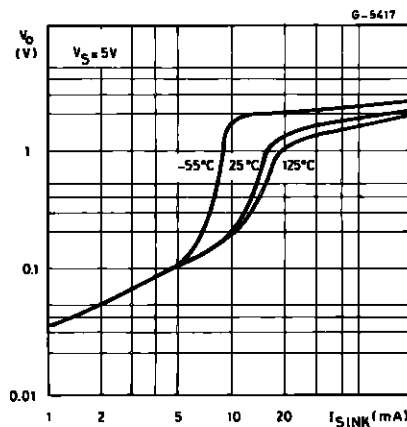
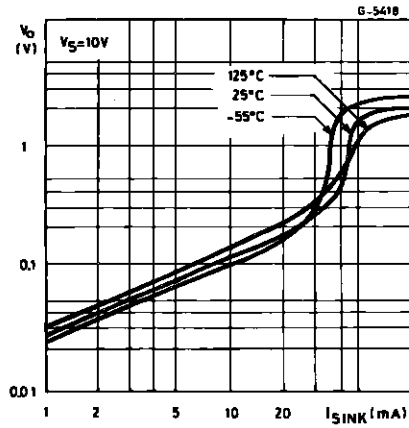
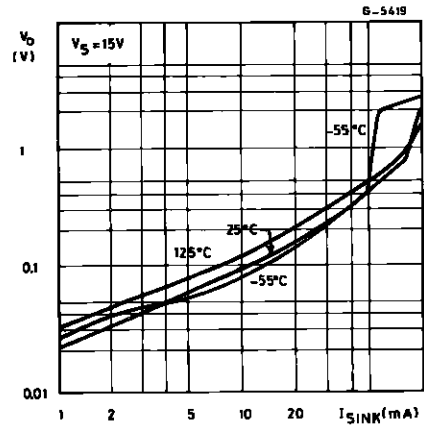
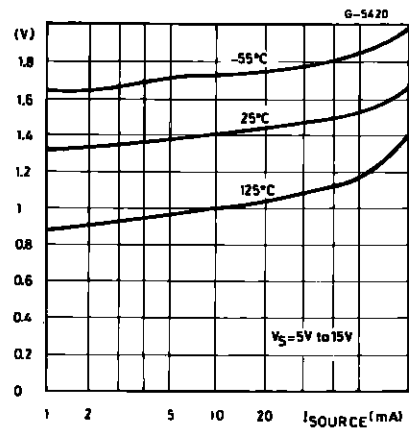


Figure 5 : Low Output Voltage versus Output Sink Current

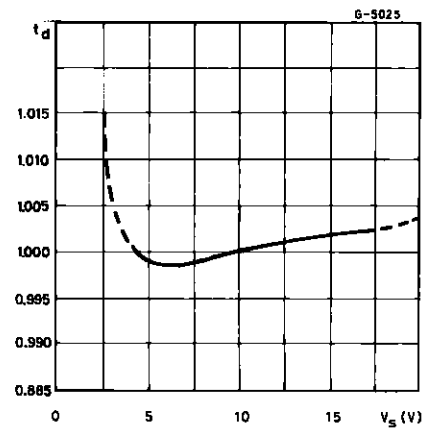
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Figure 6 : Low Output Voltage versus Output Sink Current

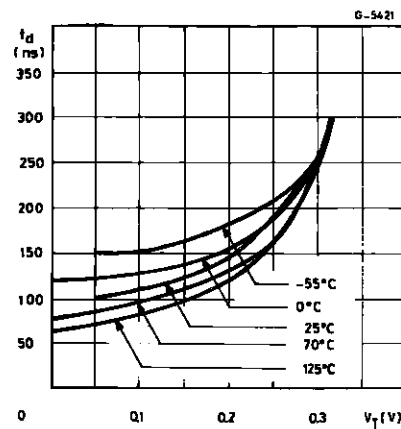
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Figure 7 : High Output Voltage Drop versus Output

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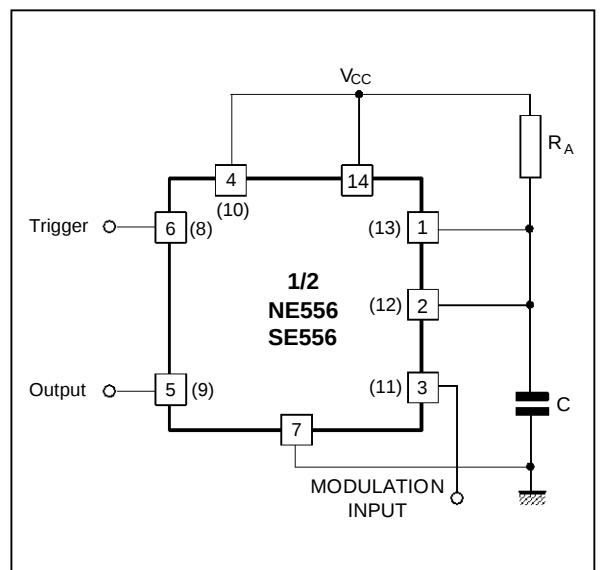
Figure 8 : Delay Time versus Supply Voltage

556-11.EPS

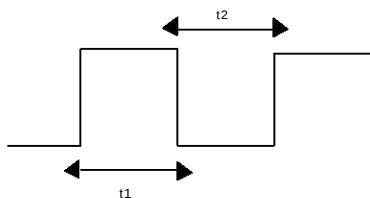
Figure 9 : Propagation Delay versus Voltage Level of Trigger Value

556-12.EPS

PULSE WIDTH MODULATOR

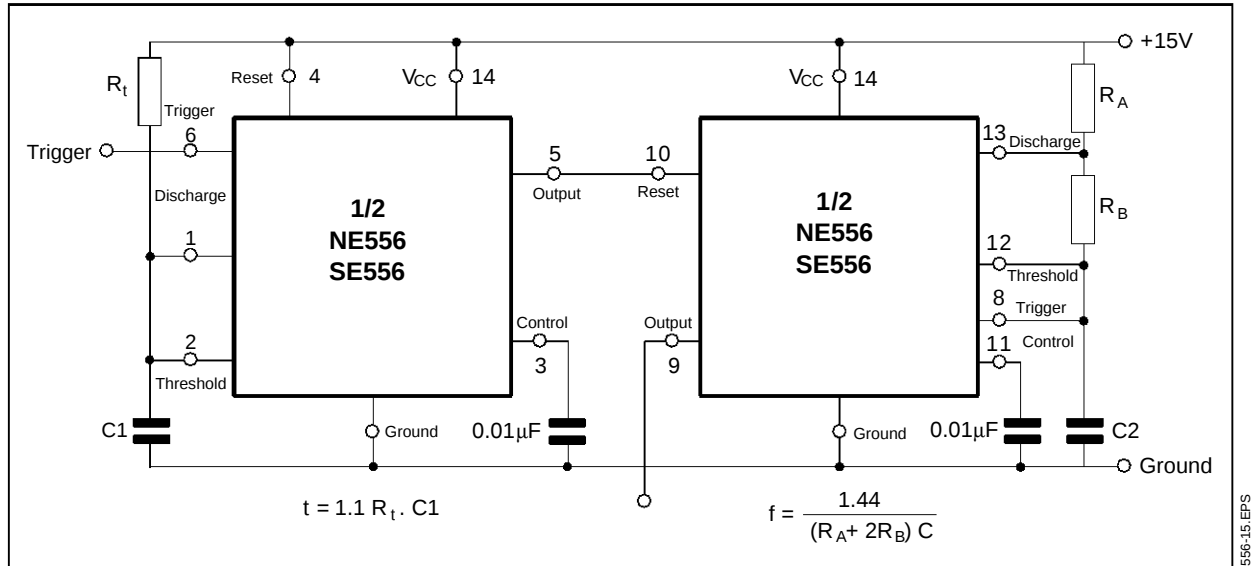


$$f = \frac{1}{t_1 + t_2} \quad R_B < \frac{1}{2} R_A \text{ ti}$$

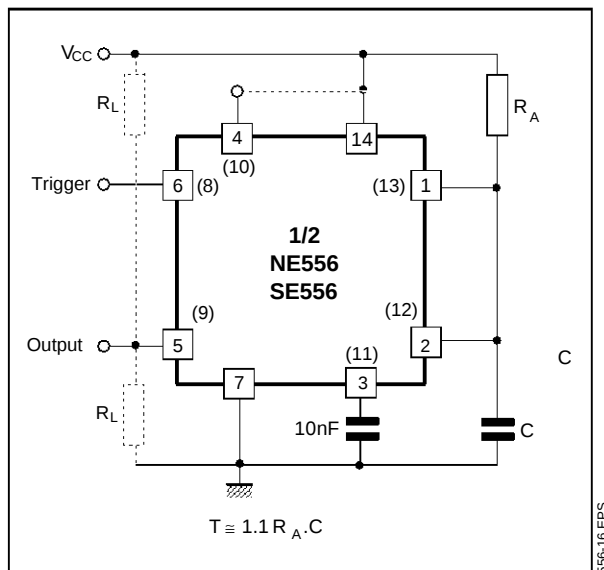


TONE BURST GENERATOR

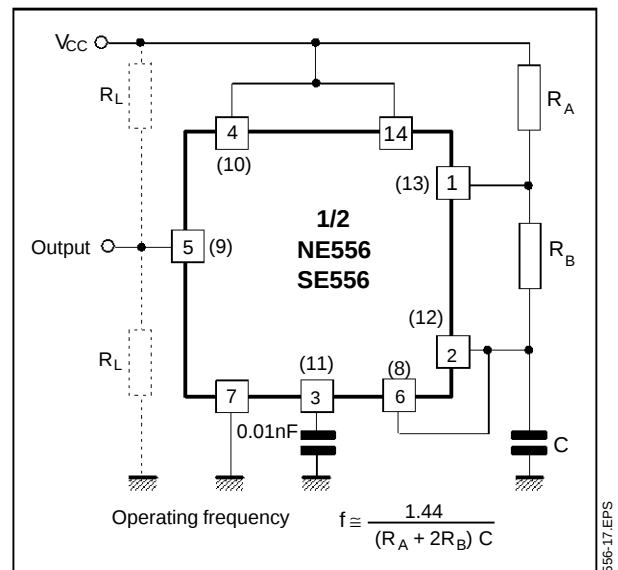
For a tone burst generator the first timer is used as a monostable and determines the tone duration when triggered by a positive pulse at pin 6. The second timer is enabled by the high output of the monostable. It is connected as an astable and determines the frequency of the tone.



MONOSTABLE OPERATION

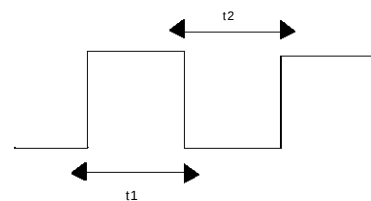


ASTABLE OPERATION

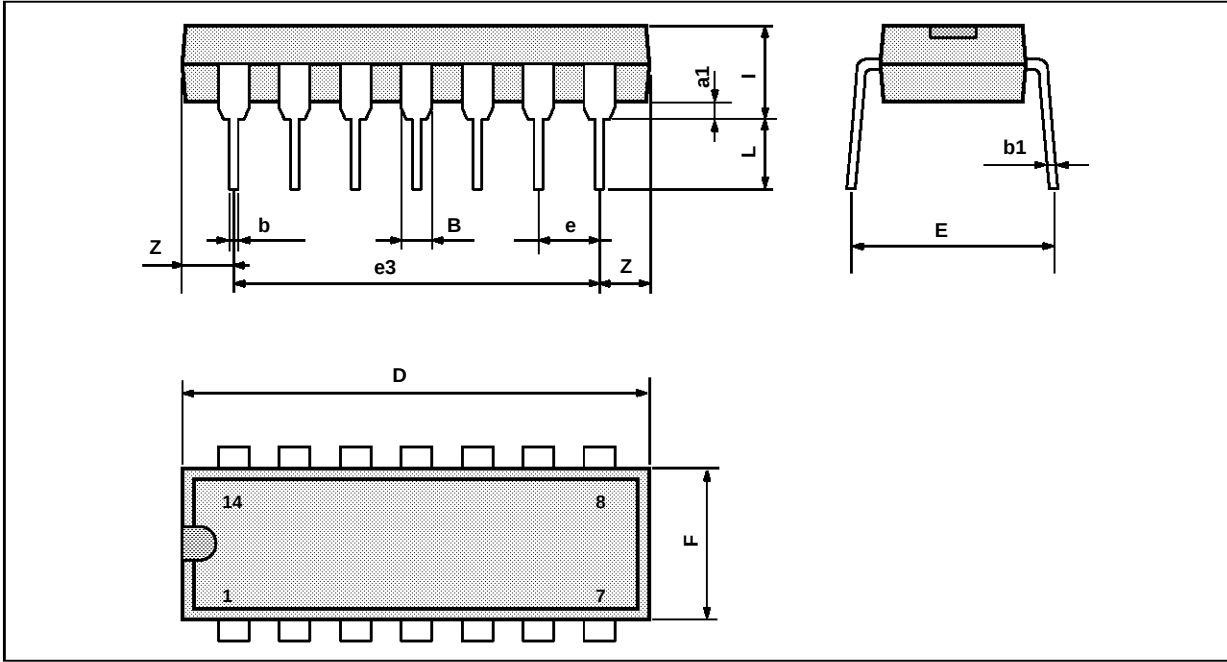


$$t_1 = 0.693 (R_A + R_B) C \text{ Output High}$$

$$t_2 = 0.693 R_B C \text{ Output low}$$

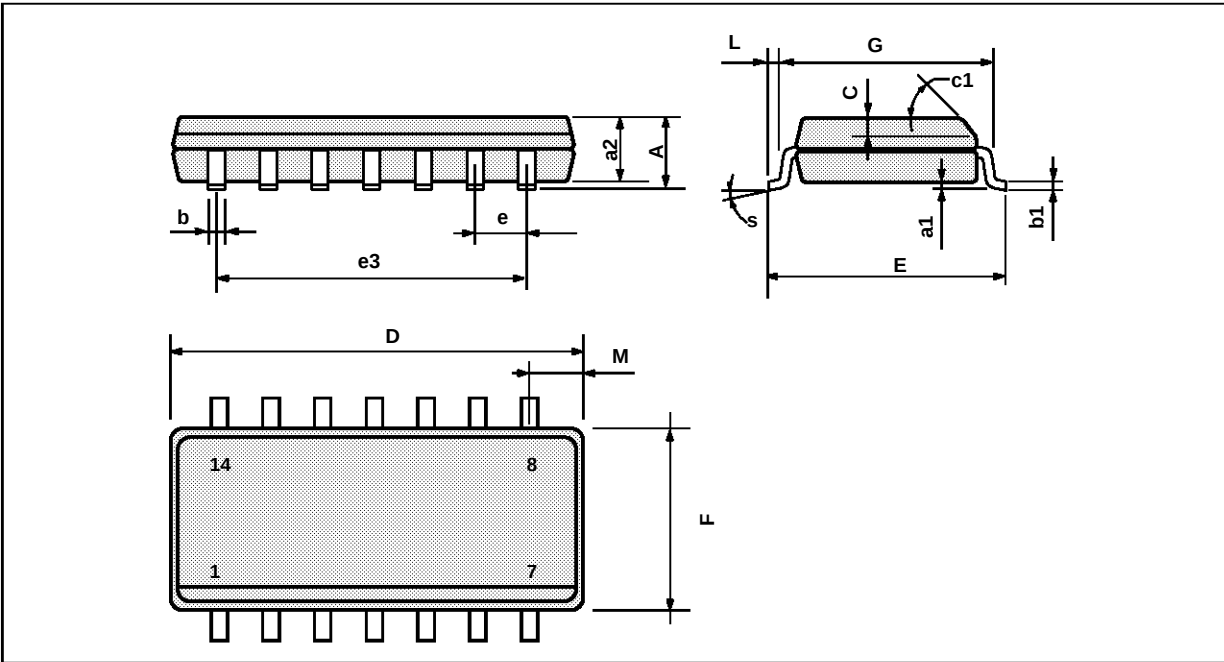


PACKAGE MECHANICAL DATA
14 PINS - PLASTIC DIP OR CERDIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA
14 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.334
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

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